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U.S. UTILITY Patent Application
O.I.P.E. PATEN

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PATENT DATE

F	APPLICATION NO.	CONT/PRIOR	CLASS	SUBCLASS	ART UNIT	EXAMINER
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ADDI ICANTS	Takashi Kar Hiroki Ohbo Nobuhiko Ha	b	, ,		•	
'in the	Method of manufactur	forming r ing nitri	nitride-b .de-based	pased semi d semicond	conductor luctor devi	layer, and method of ice PTO-2040 1289

ISSUING CLASSIFICATION						
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TERMINAL	DRAWINGS			CLAIMS ALLOWED		
DISCLAIMER	Sheets Drwg.	Figs. Drwg.	Print Fig.	Total Claims	Print Claim for O.G.	
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subsequent to (date) has been disclaimed.	(Assistant	Examiner)	(Date)			
The term of this patent shall not extend beyond the expiration date		!				
of U.S Patent. No.				ISSUE FEE		
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this patent have been disclaimed.	(Legal instrum	ents Examiner)	(Date)			
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The information disclosed herein may be res Possession outside the U.S. Patent & Trader					35, Sections 122, 181 and 368.	
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